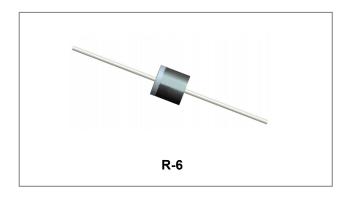


ST1550AX

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ST1550AX SCHOTTKY BARRIER RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 50 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle $@T_c$ = 75°C, rectangular wave form | 15 | А |
| Peak One Cycle Non-Repetitive Surge Current | IFSM | 8.3 ms, half Sine pulse, T_C= 25°C | 200 | A |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|-----------------------|-----------------|---|------|------|-------|
| Forward Voltage Drop* | | @ 5A, Pulse, TJ = 25 °C | 0.38 | - | |
| | V _{F1} | @ 7.5A, Pulse, TJ = 25 °C | 0.41 | - | V |
| | | @ 15A, Pulse, T」 = 25 °C | 0.48 | 0.56 | |
| | | @ 5A, Pulse, T _J = 125 °C | 0.26 | - | |
| | V _{F2} | @ 7.5A, Pulse, TJ = 125 °C | 0.31 | - | V |
| | | @ 15A, Pulse, T」 = 125 °C | 0.41 | 0.50 | |
| Reverse Current* | I _{R1} | $@V_R = rated V_{R, T_J} = 25 \ ^{\circ}C$ | 0.14 | 3 | mA |
| | I _{R2} | @V _R = rated V _R , T _J = 125 °C | 60 | 140 | mA |
| Junction Capacitance | Ст | @V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz | 1100 | - | pF |

* Pulse width < 300 μ s, duty cycle < 2%

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ST1550AX

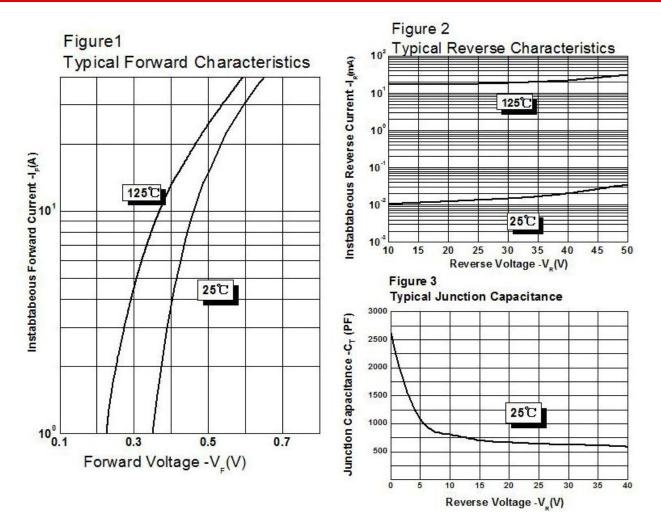
RoHS 🗭

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Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|--|------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Ambient | $R_{	heta JA}$ | DC operation | 45 | °C/W |
| Approximate Weight | wt | - | 2.24 | g |
| Case Style | | R-6 | | • |

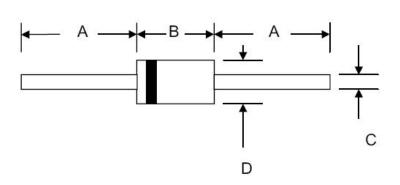
Ratings and Characteristics Curves





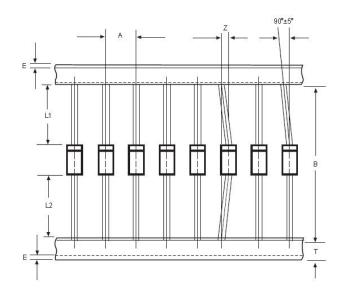
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Mechanical Dimensions R-6



| SYMBOL | Millin | neters | Inc | Inches | | |
|--------|--------|--------|-------|--------|--|--|
| STMBOL | Min. | Max. | Min. | Max. | | |
| A | 25.4 | - | 1.000 | - | | |
| В | 8.60 | 9.10 | 0.340 | 0.360 | | |
| С | 1.2 | 1.3 | 0.048 | 0.052 | | |
| D | 8.60 | 9.10 | 0.340 | 0.360 | | |

Carrier Tape Specification R-6



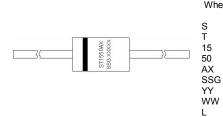
| SYMBOL | Millimeters | | |
|---------|-------------|-------|--|
| | Min. | Max. | |
| А | 9.50 | 10.50 | |
| В | 50.9 | 53.9 | |
| Z | - | 1.20 | |
| Т | 5.60 | 6.40 | |
| E | - | 0.80 | |
| IL1-L2I | _ | 1.0 | |

Ordering Information

| Device | Package | Shipping |
|----------|--------------|---------------|
| ST1550AX | R-6(Pb-Free) | 500pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

- = Device Type = Ultralow VF
- = Ontailow VP = Forward Current (15A) = Reverse Voltage (50V) = Package type = SSG

- = Year
- = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

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